NSN 5961-00-828-1005

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View Online at https://aerobasegroup.com/nsn/5961-00-828-1005 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, collector-to-base, emitter open and 25.0 breakdown voltage, collector-to-emitter, base open and 20.0 breakdown voltage, emitter-to-base, collector open and 30.0 collector to emitter voltage, dc with base short-circuited to emitter **Current Rating Per Characteristic:** 7.00 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 85.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 110.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case **Specification Data:** 80131-release4882 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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